

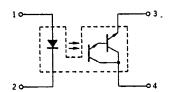
PS4001,PS4003,RS4005,PS4007,PS4009,PS4010,PS4011

PHOTO INTERRUPTER

DESCRIPTION

The PS4001, PS4003, PS4005, PS4007, PS4009 are photo coupled interrupter modules containing a GaAs light emitting diode and an NPN silicon darlington connected photo-transistor.

CONNECTION DIAGRAM (Top View)



- 1. Anode
- 3. Emitter

ABSOLUTE MAXIMUM RATINGS (Ta = 25 °C)

VR	5.0	٧
ĺF	50	mΑ
PD	100	mW
V_{CEO}	30	٧
Ic	50	mΑ
Pc	100	mW
T_{stg}	-40 to +100	°C
Topt	-20 to +80	°C
	IF PD VCEO IC PC Tstg	I _F 50 P _D 100 V _{CEO} 30 I _C 50 P _C 100 T _{stg} -40 to +100

ELECTRICAL CHARACTERISTICS (Ta = 25 °C)

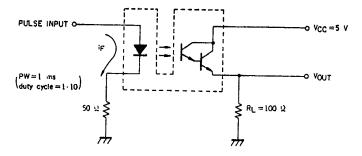
	CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Diode	Forward Voltage	٧۶		1,1	1.4	V	I _F = 20 mA
	Reverse Current	l _R		•	20	μА	VR=4.0 V
	Junction Capacitance	С		100		ρF	V=0, f=1.0 MHz
Transistor	Collector to Emitter Dark Current	CEO			400	nΑ	V _{CE} = 10 V, i _F =0
Coupled	Current Transfer Ratio	CTR(IC/IF)	20 *		ĺ	%	Ip=10 mA, VCE=2.0 V
	Collector Saturation Voltage	VCE(sat)			1.2	V	IF=10 mA, IC=0.5 mA
	Rise Time	tr		200		με	VCC=5.0 V, IC=2.0 mA, RL=100 Ω *
	Fall Time	te	-	200		με	VCC=5.0 V, IC=2.0 mA, RL=100 Ω *

[#] PS4003 . 15 % MIN., Others : 20 % MIN.

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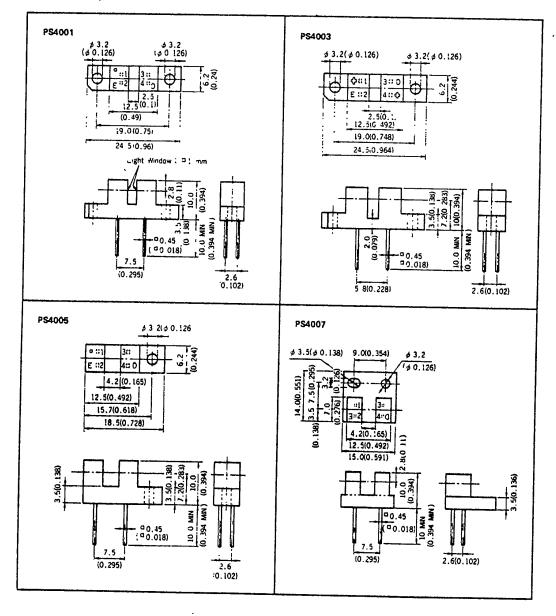
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* Test Circuit for Switching Time

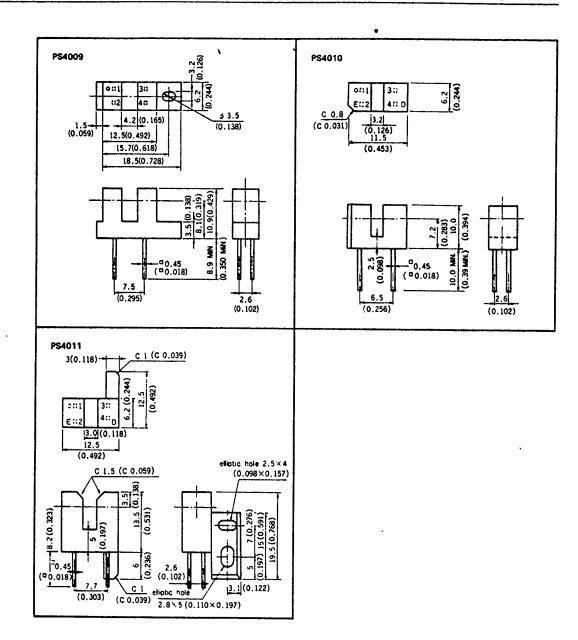


PACKAGE DIMENSIONS

in millimeters (inches)

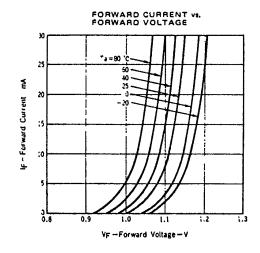


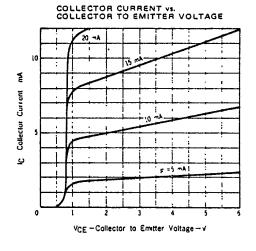
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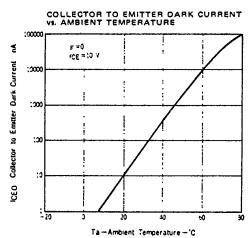


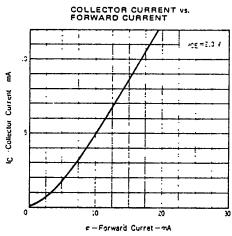
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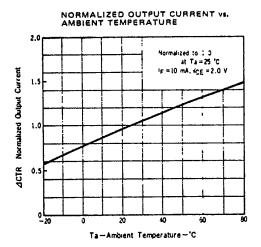
TYPICAL CHARACTERISTICS (Ta = 25 °C)

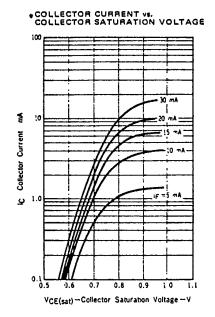


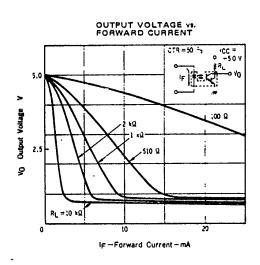


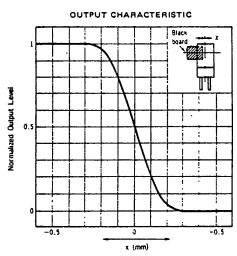




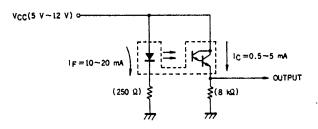








TYPICAL APPLICATION



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